2.5V Drive Nch+SBD MOS FET **US5U1**

Structure

Silicon N-channel MOS FET / Schottky barrier diode

Features

- 1) Nch MOS FET and schottky barrier diode are put in TUMT5 package.
- 2) High-speed switching, Low On-resistance.
- 3) Low voltage drive (2.5V drive).
- 4) Built-in Low VF schottky barrier diode.

Applications

Switching

Package specifications

| | Package | Taping | |
|-------|------------------------------|--------|--|
| Type | Code | TR | |
| | Basic ordering unit (pieces) | 3000 | |
| US5U1 | | 0 | |

● Absolute maximum ratings (Ta=25°C)

| <mos fet=""></mos> | | | | |
|----------------------|------------|--------------------|------|-------------|
| Parameter | Symbol | Limits | Unit | |
| Drain-source voltage | | V _{DSS} | 30 | V |
| Gate-source voltage | | V _{GSS} | 12 | V |
| Drain current | Continuous | ΙD | ±1.5 | Α |
| Drain current | Pulsed | IDP *1 | ±6.0 | A |
| Source current | Continuous | Is | 0.75 | A |
| (Body diode) | Pulsed | I _{SP} *1 | 6.0 | Α |
| Power dissipation | | P _D *2 | 0.7 | W / ELEMENT |
| Channel temperature | | Tch | 150 | °C |

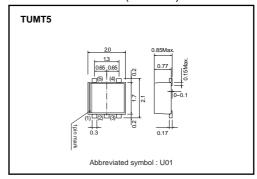
^{*1} Pw≤10µs, Duty cycle≤1% *2 Mounted on a ceramic board

<Di>

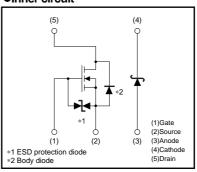
| Parameter | Symbol | Limits | Unit |
|---------------------------------|---------------------|--------|-------------|
| Repetitive peak reverse voltage | VRM | 30 | V |
| Reverse voltage | VR | 20 | V |
| Forward current | IF | 0.5 | Α |
| Forward current surge peak | I _{FSM} *1 | 2.0 | A |
| Power dissipation | P _D *2 | 0.5 | W / ELEMENT |
| Junction temperature | Tj | 150 | °C |

^{*1 60}Hz •1cycle *2 Mounted on ceramic board

●External dimensions (Unit : mm)



•Inner circuit



<MOS FET and Di>

| Parameter | Symbol | Limits | Unit | |
|------------------------------|-------------------|-------------|-----------|--|
| Total power dissipation | P _D *1 | 1.0 | W / TOTAL | |
| Range of storage temperature | Tstg | -55 to +150 | °C | |

^{*1} Mounted on a ceramic board

●Electrical characteristics (Ta=25°C)

<MOS FET>

| Parameter | Symbol | Min. | Тур. | Max. | Unit | Conditions |
|---|------------------------|------|------|------|------|--|
| Gate-source leakage | I _{GSS} | _ | - | 10 | μΑ | V _{GS} =12V, V _{DS} =0V |
| Drain-source breakdown voltage | V _{(BR) DSS} | 30 | _ | _ | V | I _D = 1mA, V _{GS} =0V |
| Zero gate voltage drain current | IDSS | _ | _ | 1 | μΑ | Vps= 30V, Vgs=0V |
| Gate threshold voltage | VGS (th) | 0.5 | _ | 1.5 | V | VDS= 10V, ID= 1mA |
| Otatia duale accusa as atata | | - | 170 | 240 | mΩ | I _D = 1.5A, V _{GS} = 4.5V |
| Static drain-source on-state resistance | R _{DS (on)} * | - | 180 | 250 | mΩ | I _D = 1.5A, V _{GS} = 4V |
| | | - | 240 | 340 | mΩ | I _D = 1.5A, V _{GS} = 2.5V |
| Forward transfer admittance | Y _{fs} * | 1.5 | _ | _ | S | V _{DS} = 10V, I _D = 1.5A |
| Input capacitance | Ciss | - | 80 | _ | pF | V _{DS} = 10V |
| Output capacitance | Coss | _ | 14 | _ | pF | V _{GS} =0V |
| Reverse transfer capacitance | Crss | - | 12 | _ | pF | f=1MHz |
| Turn-on delay time | t _{d (on)} * | - | 7 | _ | ns | V _{DD} ≒ 15V |
| Rise time | tr * | - | 9 | _ | ns | I _D = 0.75A V _G s= 4.5V |
| Turn-off delay time | t _{d (off)} * | _ | 15 | _ | ns | $R_{I} = 20\Omega$ |
| Fall time | t _f * | _ | 6 | _ | ns | R _G =10Ω |
| Total gate charge | Qg * | _ | 1.6 | 2.2 | nC | V _{DD} = 15V, V _{GS} = 4.5V |
| Gate-source charge | Qgs * | - | 0.5 | _ | nC | ID= 1.5A |
| Gate-drain charge | Q _{gd} * | _ | 0.3 | _ | nC | $R_L=10\Omega$, $R_G=10\Omega$ |

*Pulsed

<Body diode characteristics (Source-drain)>

| Parameter | Symbol | Min. | Тур. | Max. | Unit | Conditions |
|-----------------|--------|------|------|------|------|--------------------------------|
| Forward voltage | Vsp | - | _ | 1.2 | V | Is= 0.75A, V _{GS} =0V |

<Di>

| Parameter | Symbol | Min. | Тур. | Max. | Unit | Conditions |
|-----------------|--------|------|------|------|------|----------------------|
| Forward voltage | VF | - | _ | 0.36 | V | Is= 0.1A |
| | | - | _ | 0.47 | V | Is= 0.5A |
| Reverse current | lR | _ | _ | 100 | μΑ | I _S = 20V |

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